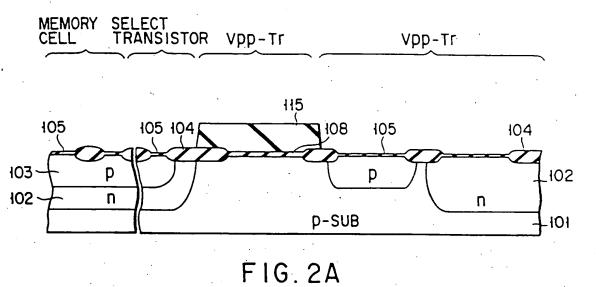
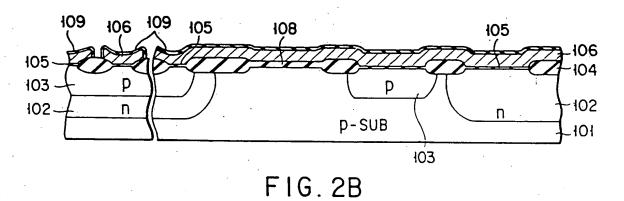


F16.3

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 2 of 25

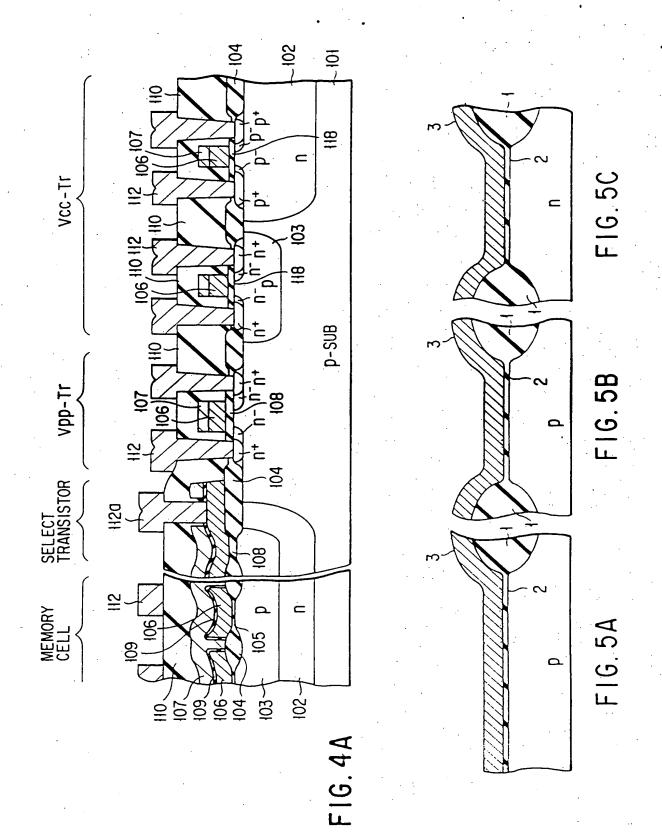




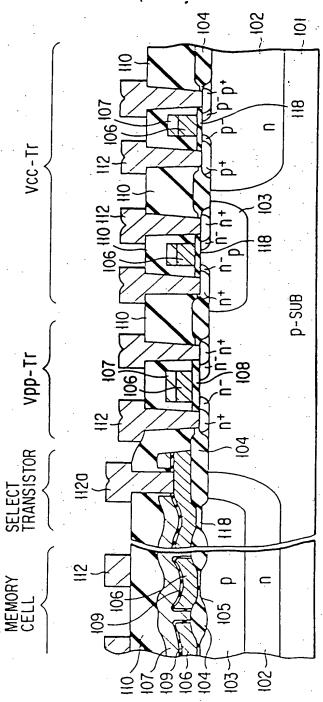
107 109 109 105 p 102 n 101

FIG. 2C

HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 3 of 25

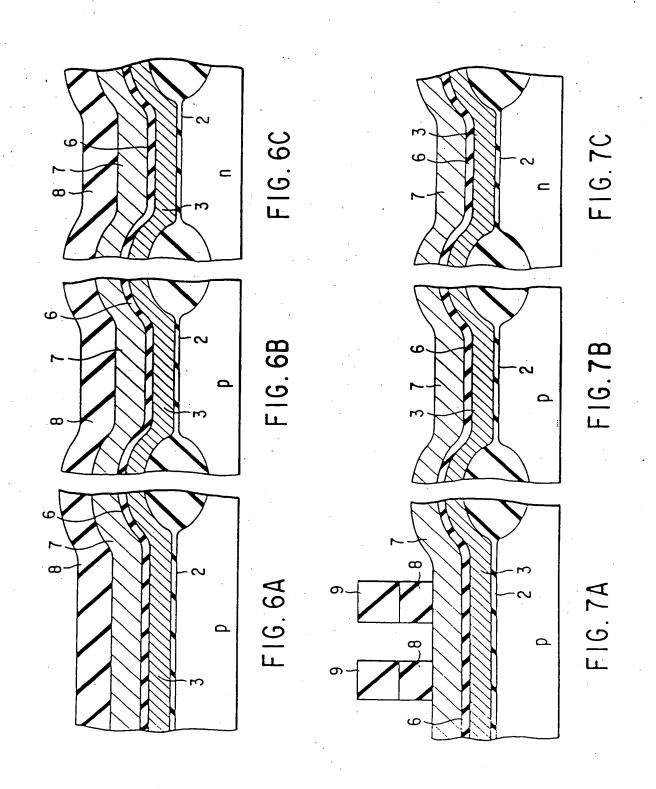


HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 4 of 25

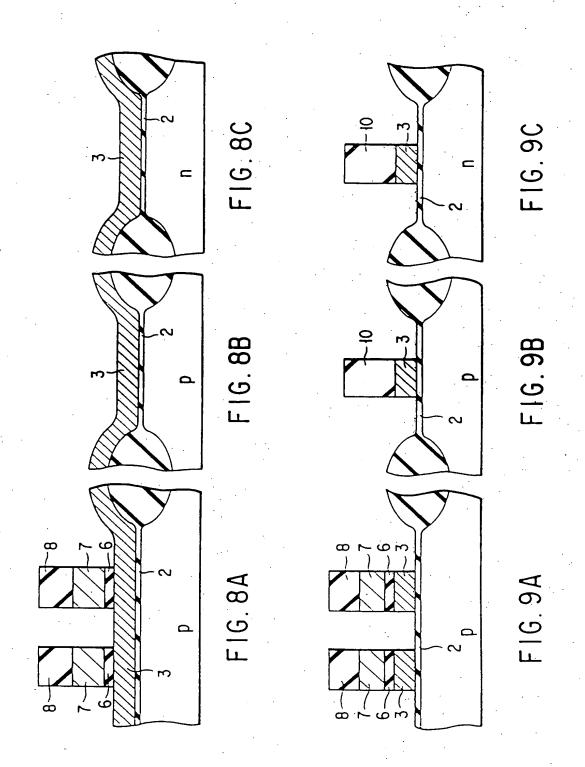


F16.4B

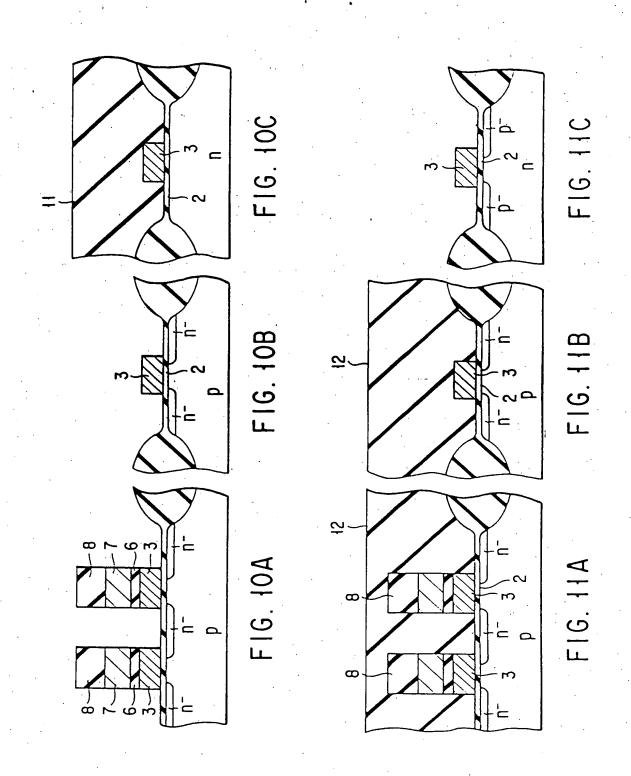
HOGAN & HARTSON - 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 5 of 25



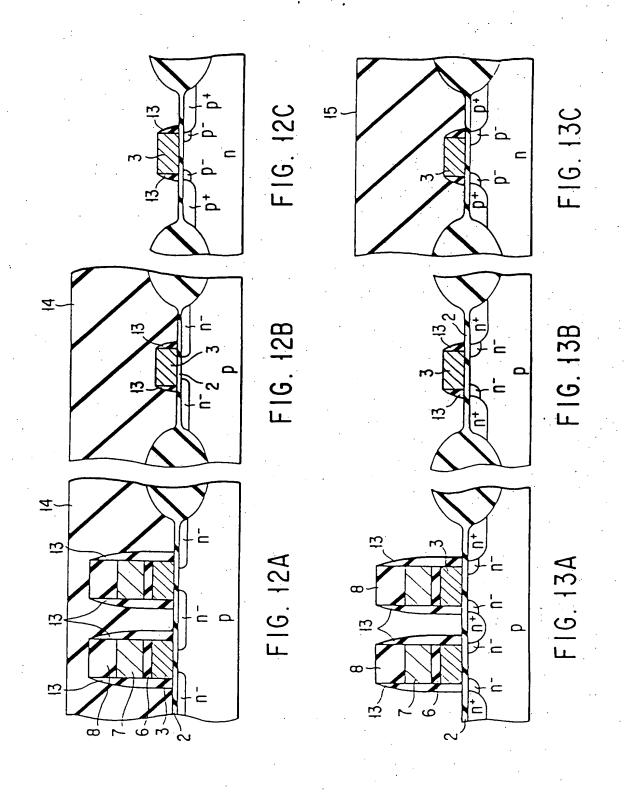
HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 6 of 25



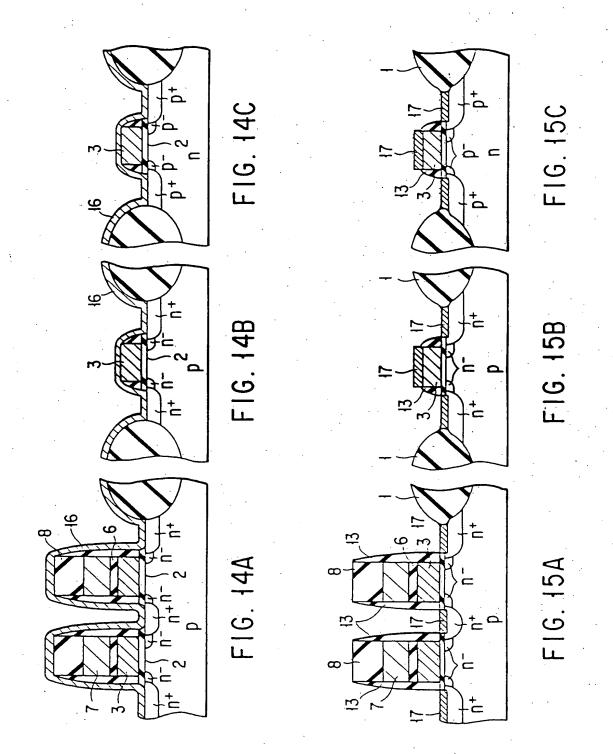
HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 7 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 8 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 9 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 10 of 25

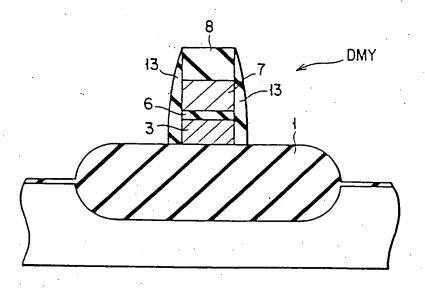


FIG. 16A

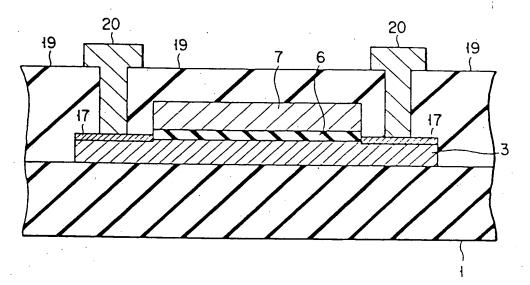
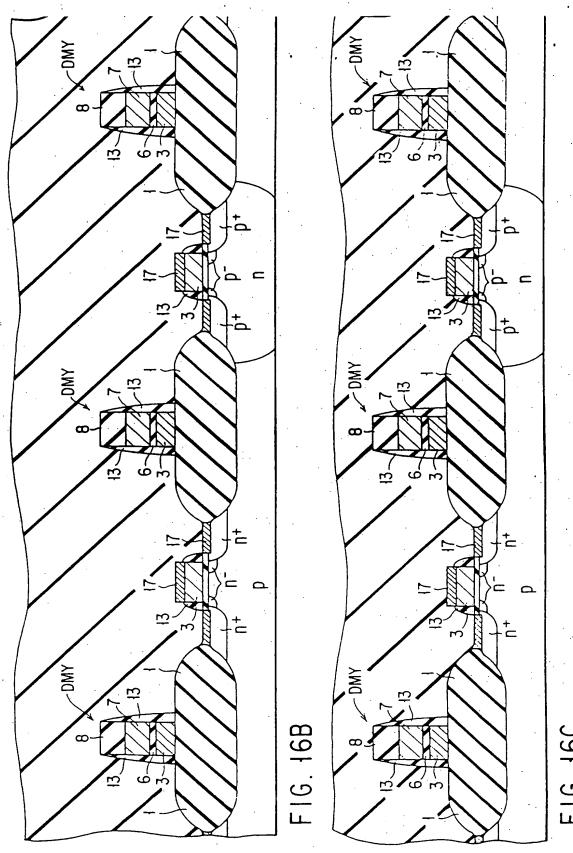


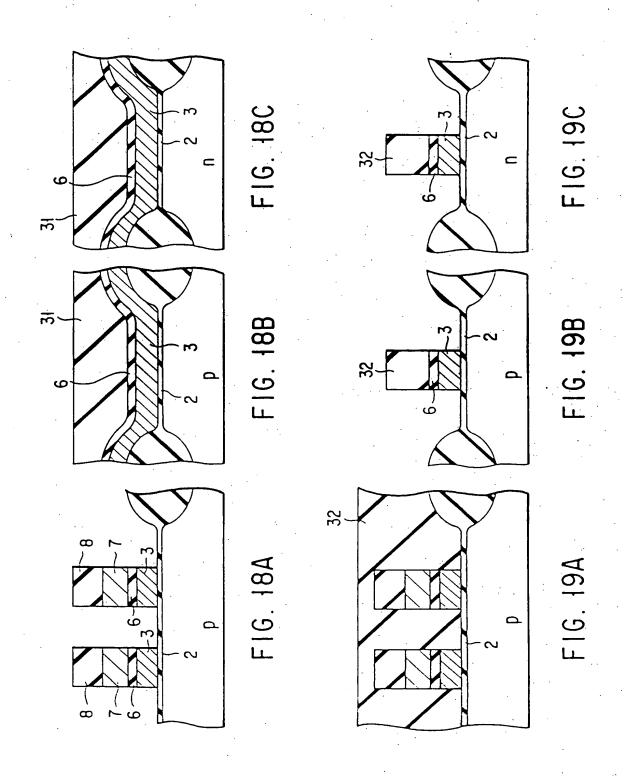
FIG. 17

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 11 of 25

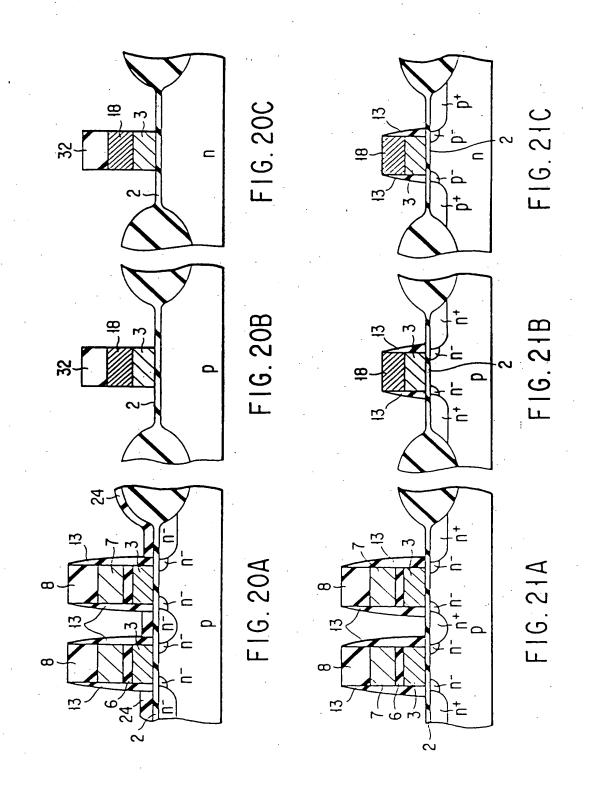


F16. 16C

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 12 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 13 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 14 of 25

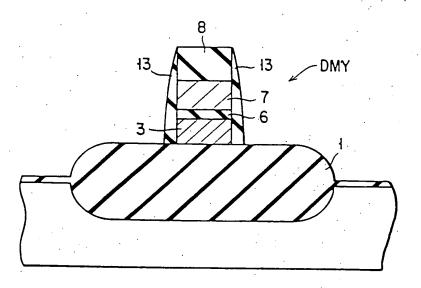


FIG. 22

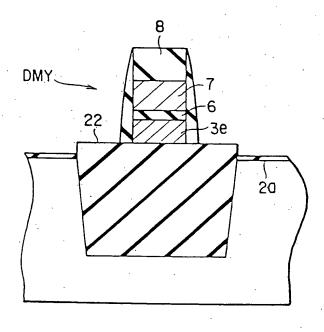
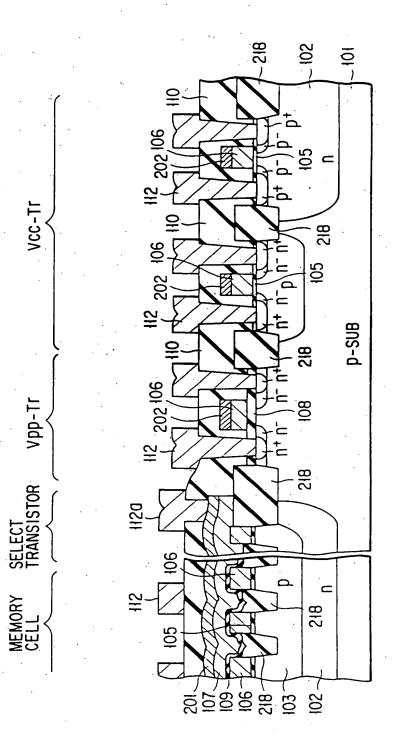


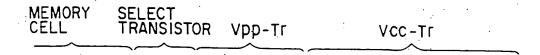
FIG. 29

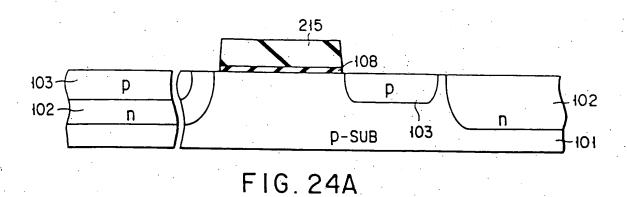
HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 15 of 25



F16.23

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 16 of 25





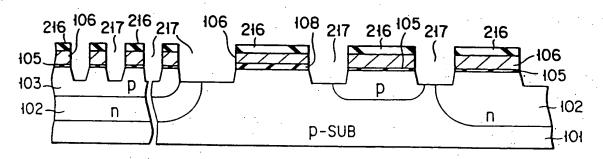


FIG. 24B

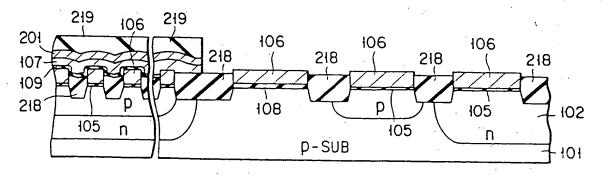
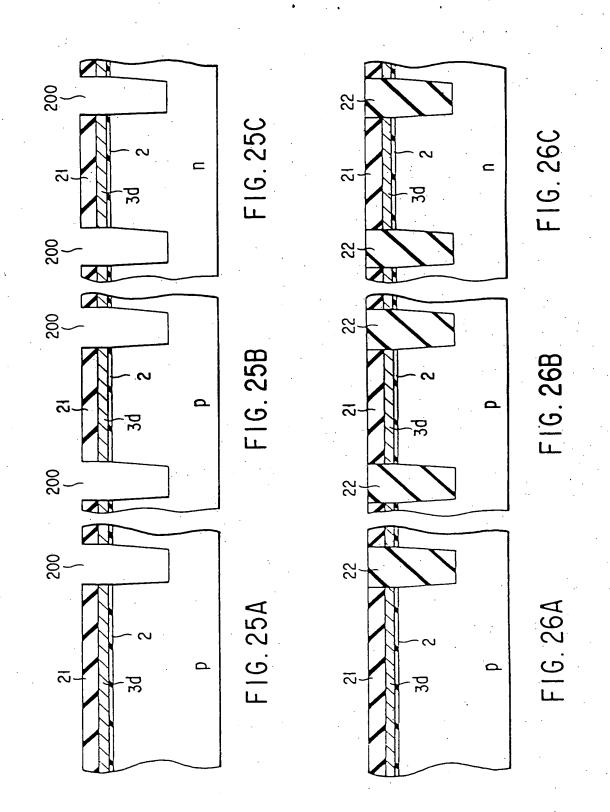
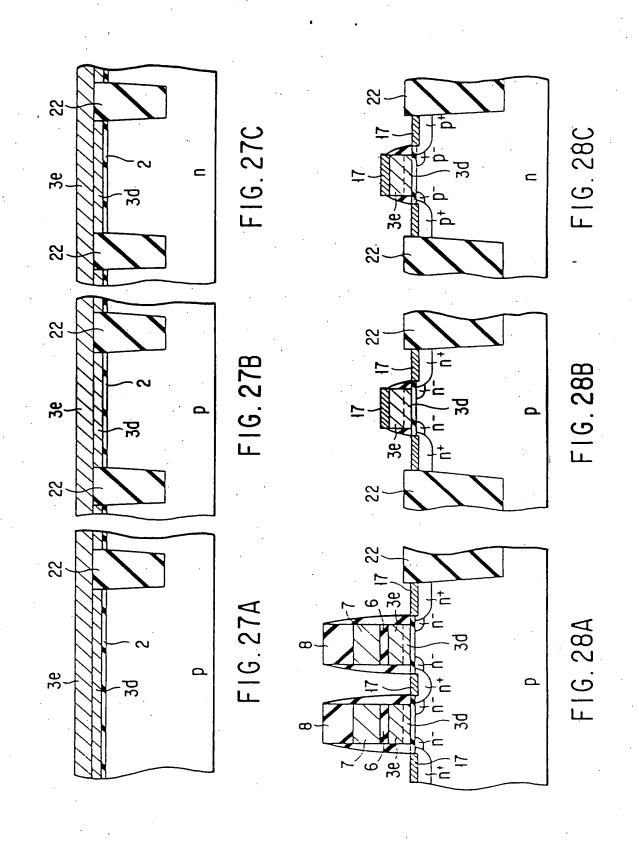


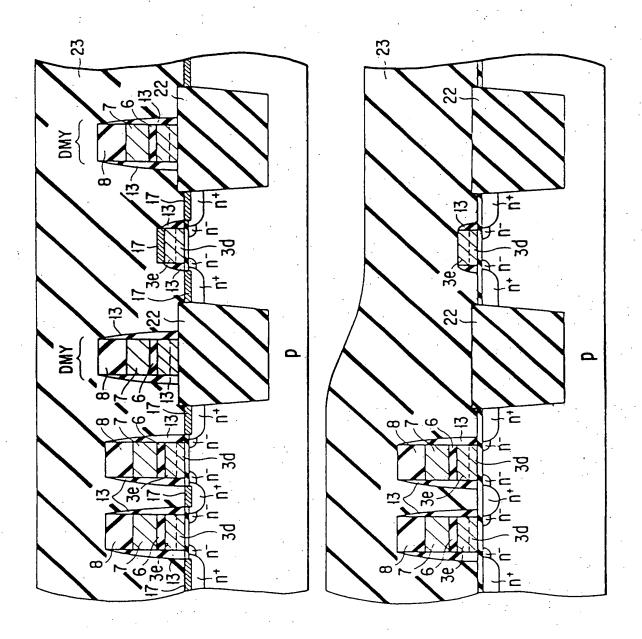
FIG. 240

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 17 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 18 of 25





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HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 20 of 25

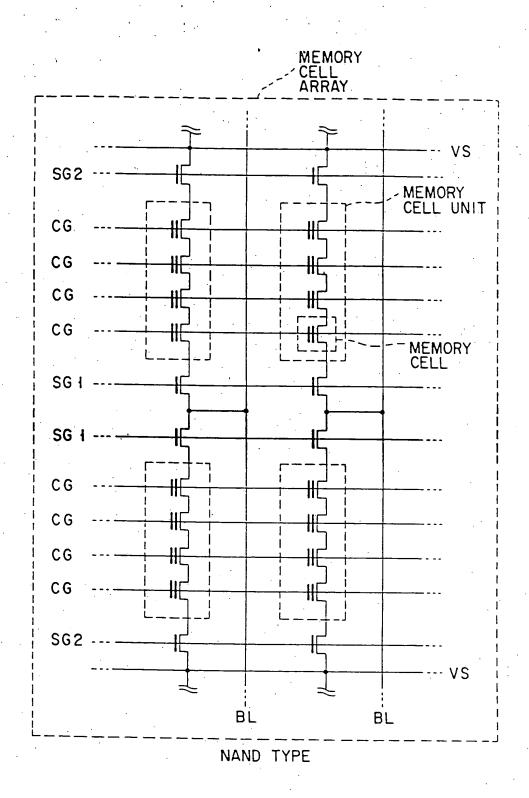


FIG. 32

HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 21 of 25

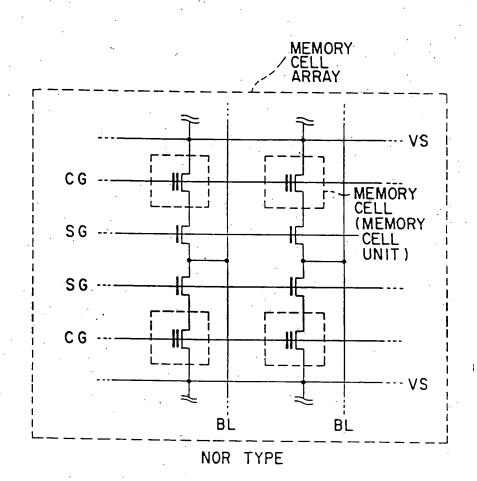
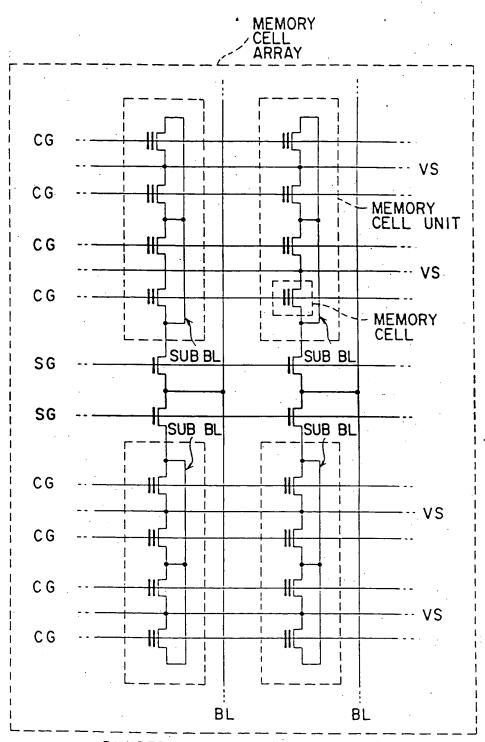


FIG. 33

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 22 of 25



DIVIDED NOR TYPE (DINOR TYPE)

FIG. 34

HOGAN & HARTSON - 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 23 of 25

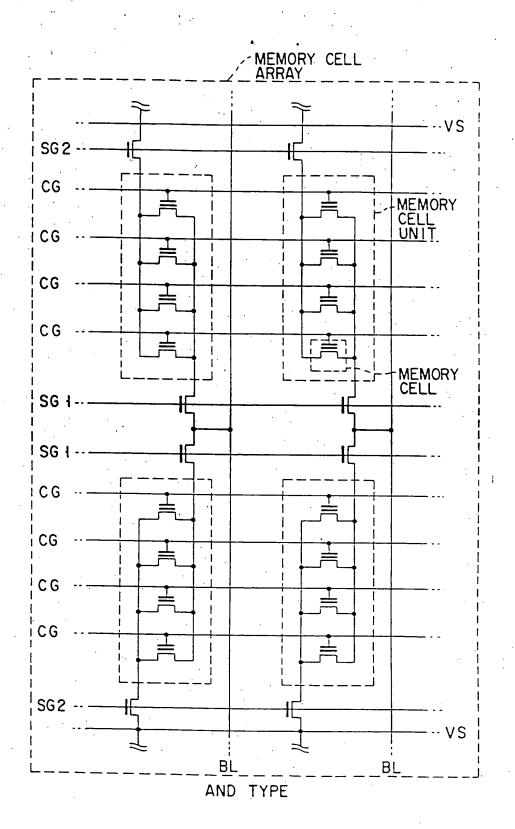
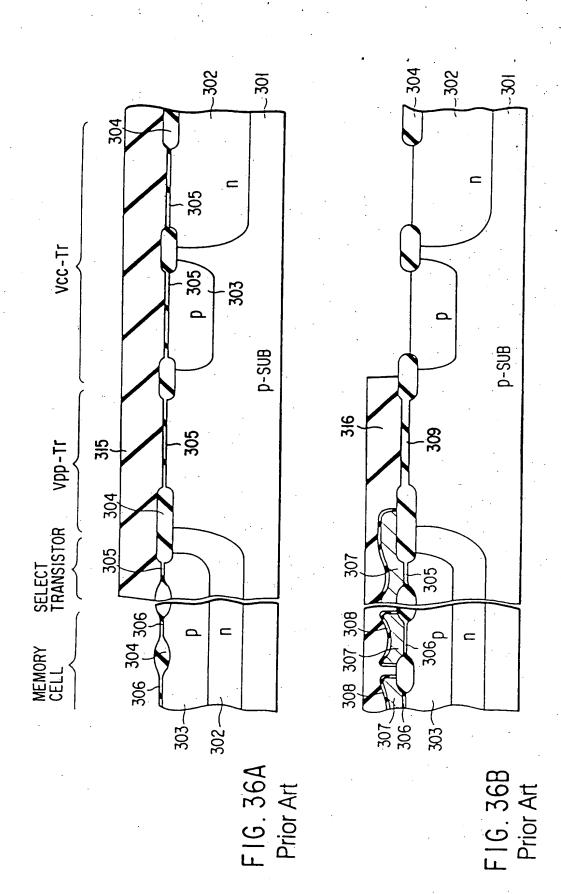


FIG. 35

HOGAN & HARTSON – 81790.0311
YAEGASHI, et al., "Non-Volatile
Semiconductor Memory Device and Its
Manufacturing Method"
EV 324 111 313 US
Page 24 of 25



HOGAN & HARTSON – 81790.0311 YAEGASHI, et al., "Non-Volatile Semiconductor Memory Device and Its Manufacturing Method" EV 324 111 313 US Page 25 of 25

